

16

114

210

41<u>0</u>

6 211 310

10 311

13

15



Data sheet acquired from Harris Semiconductor SCHS283

AC/ACT

158

1Y

2Y

3Y

47

92C8-42383

AC/ACT

157

1 1

21

31

**FUNCTIONAL DIAGRAM** 



## **Quad 2-Input Multiplexers**

AC/ACT157 - Non-Inverting AC/ACT158 - Inverting

### **Type Features:**

Buffered inputs

Typical propagation delay (AC/ACT158): 3.8 ns @ Vcc = 5 V, T<sub>A</sub> = 25° C, C<sub>L</sub> = 50 pF

The RCA CD54/74AC157, -158 and CD54/74ACT157, -158 quad 2-input multiplexers use the RCA ADVANCED CMOS technology. Both circuits can select four bits of data from two sources under the control of a common select input (S). The Enable input (E) is active LOW. When E is HIGH, all of the outputs of the 158 are forced HIGH and in the 157, all of the outputs are forced LOW, regardless of all other input conditions.

The CD74AC/ACT157 and CD74AC/ACT158 are supplied in 16-lead dual-in-line plastic packages (E suffix) and in 16lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC157, -158 and CD54ACT157, -158, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

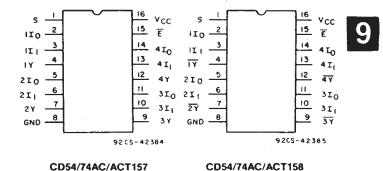
**TRUTH TABLE** 

#### **Family Features:**

- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST®/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply.
- ± 24-mA output drive current
  - Fanout to 15 FAST® ICs
  - Drives 50-ohm transmission lines

	Select	Đa	ata	Output			
Enable	Input	Inp	uts	157	158		
Ē	S	I.	11	Y	Ϋ́		
н	х	X	X	L	Н		
L	L	L	X	L	н		
L	L	н	x	н	L		
L	н	х	L	L	н		
L	н	X	н	н	L L		

H = High level, L = Low level, X = Don't care



This data sheet is applicable to the CD54/74AC157 and CD74AC158. The CD54AC158, CD54AC157, and CD54ACT158 were not acquired from Harris Semiconductor. See SCHS238 for information on the CD74ACT157 and CD74ACT158.

## Technical Data \_\_\_\_\_\_ CD54/74AC157, CD54/74AC158 CD54/74ACT157, CD54/74ACT158

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE (V <sub>cc</sub> ) DC INPUT DIODE CURRENT, I <sub>IK</sub> (for V <sub>1</sub> < -0.5 V or V <sub>1</sub> > V <sub>cc</sub> + 0.5 V) DC OUTPUT DIODE CURRENT, I <sub>oK</sub> (for V <sub>0</sub> < -0.5 V or V <sub>0</sub> > V <sub>cc</sub> + 0.5 V) DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, I <sub>0</sub> (for V <sub>0</sub> > -0.5 V or V <sub>0</sub> DC V <sub>cc</sub> or GROUND CURRENT (I <sub>cc</sub> or I <sub>GND</sub> )	±20 mA ±50 mA < V <sub>CC</sub> + 0.5 V)±50 mA
POWER DISSIPATION PER PACKAGE ( $P_{D}$ ):	
For $T_A = -55$ to $+100^{\circ}$ C (PACKAGE TYPE E)	
For T <sub>A</sub> = +100 to +125°C (PACKAGE TYPE E)	
For $T_A = -55$ to $+70^{\circ}$ C (PACKAGE TYPE M)	
For $T_A = +70$ to $+125^{\circ}$ C (PACKAGE TYPE M)	Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (TA)	
STORAGE TEMPERATURE (Tstg)	65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 $\pm$ 1/32 in. (1.59 $\pm$ 0.79 mm) from case for 10 s maximum	
Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contactir	ng lead tips only +300°C
$^{\circ}$ For up to 4 outputs per device; add $\pm$ 25 mA for each additional output.	

#### **RECOMMENDED OPERATING CONDITIONS:**

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

	LIN	IITS		
CHARACTERISTIC	MIN.	MAX.		
Supply-Voltage Range, Vcc*: (For T <sub>A</sub> = Full Package-Temperature Range) AC Types	1.5	5.5	v	
ACT Types	4.5	5.5 V <sub>cc</sub>		
Operating Temperature, T <sub>A</sub>	-55	+125	°C	
Input Rise and Fall Slew Rate, dt/dv at 1.5 V to 3 V(AC Types) at 3.6 V to 5.5 V(AC Types) at 4.5 V to 5.5 V(ACT Types)	0 0 0	50 20 10	ns/V ns/V ns/V	

\*Unless otherwise specified, all voltages are referenced to ground.

# **Technical Data** CD54/74AC157, CD54/74AC158 CD54/74ACT157, CD54/74ACT158

	STATIC ELECTRICAL	CHARACTERISTICS: AC Series
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					AMBIENT TEMPERATURE (TA) - °C						
CHARACTERISTICS	TEST CONDITIONS		V <sub>cc</sub>	+25		-40 to +85		-55 to +125			
		V, (V)	l <sub>o</sub> (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	1
High-Level Input				1.5	1.2	- 1	1.2		1.2	-	1
Voltage	ViH			3	2.1	-	2.1	-	2.1	- 1	1 v
				5.5	3.85	-	3.85		3.85	_	1
Low-Level Input				1.5	_	0.3		0.3		0.3	1
Voltage	ViL			3	—	0.9		0.9		0.9	1 v
				5.5	-	1.65	-	1.65		1.65	1
High-Level Output		•	-0.05	1.5	1.4	-	1.4	T _	1.4	-	1
Voltage	Vон	ViH	-0.05	3	2.9	-	2.9	·	2.9		1
		or	-0.05	4.5	4.4		4.4		4.4	-	1
		VIL	-4	3	2.58	-	2.48	_	2.4		1 v
			-24	4.5	3.94	-	3.8	-	3.7	-	1
		#, * {	-75	5.5		<u> </u>	3.85			_	1
		<u> </u>	-50	5.5		_	_	_	3.85	_	
Low Level Output			0.05	1.5	—	0.1		0.1		0.1	
Voltage	Vol	VIH	0.05	3	—	0.1		0.1	_	0.1	
		or	0.05	4.5	_	0.1	—	0.1	_	0.1	
		ViL	12	3	-	0.36	_	0.44		0.5	v
			24	4.5		0.36		0.44		0.5	
		#, * {	75	5.5		_	_	1.65	_	-	
		<u> </u>	50	5.5	—	—	-	—	_	1.65	1
Input Leakage Current	l <sub>t</sub>	V <sub>cc</sub> or GND		5.5		±0.1		±1	—	±1	μA
Quiescent Supply Current, MSI	امد	V <sub>cc</sub> or GND	0	5.5		8		80		160	μA

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation. \* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

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## Technical Data \_\_\_\_\_\_ CD54/74AC157, CD54/74AC158 CD54/74ACT157, CD54/74ACT158

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

3

	_			AMBIENT TEMPERATURE (TA) - °C							
CHARACTERISTICS		TEST CONDITIONS		V <sub>cc</sub>	+25		-40 to +85		-55 to +125		UNITS
		V, (V)	l <sub>o</sub> (mA)	(Ŭ)	MIN.	MIN. MAX.	. MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage	ViH			4.5 to 5.5	2	-	2	_	2	-	v
Low-Level Input Voltage	ViL			4.5 to 5.5	—	0.8	-	0.8	_	0.8	v
High-Level Output		VIH	-0.05	4.5	4.4	-	4.4		4.4	-	
Voltage	Vон	or ViL	-24	4.5	3.94		3.8	—	3.7		l v l
		#. * {	-75	5.5	_		3.85	—			
		<b>"</b> '	-50	5.5	_	-		—	3.85		
Low-Level Output		ViH	0.05	4.5	_	0.1		0.1		0.1	
Voltage	Vol	or Vil	24	4.5	_	0.36	—	0.44		0.5	l v
		#, * {	75	5.5	-	-		1.65			
		/ "' {	50	5.5	—				<u> </u>	1.65	
Input Leakage Current	ł,	V <sub>cc</sub> or GND		5.5	_	±0.1	_	±1		±1	μA
Quiescent Supply Current, MSI	lcc	V <sub>cc</sub> or GND	0	5.5		8	-	80		160	μA
Additional Quiescent Current per Input P TTL Inputs High 1 Unit Load		V <sub>cc</sub> -2.1		4.5 to 5.5		2.4		2.8	_	3	mA

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

\* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

#### ACT INPUT LOADING TABLE

	UNIT LOAD*				
INPUT	157	158			
ł (All)	0.37	0.37			
Ē	0.83	0.83			
S	1.33	1.33			

\*Unit load is  $\Delta I_{CC}$  limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25°C.

## **Technical Data** CD54/74AC157, CD54/74AC158 CD54/74ACT157, CD54/74ACT158

SWITCHING CHARACTERISTICS: AC Series; t,, t, = 3 ns, CL = 50 pF

				AMBI	ENT TEMPE	RATURE (T	·▲) - °C	
CHARACTERISTICS		SYMBOL	V <sub>cc</sub> (V)		o +85		+125	
				MIN.	MAX.	MIN.	MAX.	1
Propagation Delays: Data to Output	(157)	t <sub>PLH</sub> t <sub>PHL</sub>	1.5 3.3* 5†	3.2 2.2	97 10.8 7.7		106 11.9 8.5	ns
Enable to Output	(157)	t <sub>PLH</sub> t <sub>PHL</sub>	1.5 3.3 5	— 5.1 3.6	154 17.2 12.3	 4.7 3.4	169 18.9 13.5	ns
Select to Output	(157)	t <sub>PLH</sub> t <sub>PHL</sub>	1.5 3.3 5	 5.4 3.8	164 18.5 13.2	 5.1 3.6	180 20.3 14.5	ns
Data to Output	(158)	tегн tенг	1.5 3.3 5		91 12.8 7.3	 2.8 2	100 11.2 8	กร
Enable to Output	(158)	тецн тенц	1.5 3.3 5	 4.5 3.2	135 15.2 10.8	4.2 3	149 16.7 11.9	ns
Select to Output	(158)	tегн tенг	1.5 3.3 5	 4.9 3.5	147 16.5 11.7	4.5 3.2	161 18.1 12.9	ns
Power Dissipation Capacitance	(157) (158)	С <sub>РФ</sub> §	—	156 Тур. 149 Тур.		156 Тур. 149 Тур.		pF
Input Capacitance		Ci			10	-	10	pF

 $\pi_{D_{n}}^{(1)}$ 

SWITCHING CHARACTERISTIS: ACT Series; t,, t, = 3 ns, CL = 50 pF

CHARACTERISTICS		1 1	V <sub>cc</sub> (V)	AN				
		SYMBOL		-40 1	to +85	-55 te	o +125	
				MIN.	MAX.	MIN.	MAX.	
Propagation Delays: Data to Output	(157)	трін трні	5†	2.5	8.6	2.4	9.5	ns
Enable to Output	(157)	tрін tphi	5	3.6	12.3	3.4	13.5	ns
Select to Output	(157)	tрін tрні	5	3.8	13.2	3.6	14.5	ns
Data to Output	(158)	tрін tрні	5	2.4	8.4	2.3	9.2	ns
Enable to Output	(158)	tplh tphl	5	3.3	11.3	3.1	12.4	ns
Select to Output	(158)	tplh tphL	5	3.6	12.3	3.4	13.5	ns
Power Dissipation Capacitance	(157) (158)	C <sub>PD</sub> §		156 Тур. 149 Тур.				pF
Input Capacitance		Cı		_	10	_	10	pF

\*3.3 V: min. is @ 3.6 V

t5 V: min. is @ 5.5 V max. is @ 4.5 V

max. is @ 3 V

where  $f_i = input$  frequency

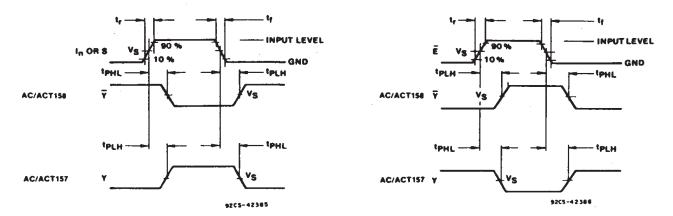
 $f_0 = output frequency$ 

 $C_L$  = output load capacitance

V<sub>cc</sub> = supply voltage.

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## Technical Data CD54/74AC157, CD54/74AC158 CD54/74ACT157, CD54/74ACT158



	CD54/74AC	CD54/74ACT
Input Level	Vcc	3 V
Input Switching Voltage, Vs	0.5 V <sub>CC</sub>	1.5 V
Output Switching Voltage, Vs	0.5 V <sub>cc</sub>	0.5 Vcc

Fig. 3 - Inputs or select to output propagation delays.

Fig. 4 - Enable to output propagation delays.

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